## **Transmissive Sensor**

#### **FEATURES**

- · Phototransistor output
- Four mounting configurations
- · Accurate position sensing
- 0.125 in.(3.18 mm) slot width
- Choice of detector aperture
- 24.0 in.(610 mm) min. 26 AWG UL 1429 wire
- · Choice of opaque or IR transmissive housings

#### **DESCRIPTION**

The HOA088X/089X series consists of an infrared emitting diode facing an NPN silicon phototransistor encased in a black thermoplastic housing. Phototransistor switching takes place whenever an opaque object passes through the slot between emitter and detector. This series allows the user to choose from available options: (1) mounting tab configuration, (2) detector aperture size, (3) electro-optical characteristics, and (4) housing materials.

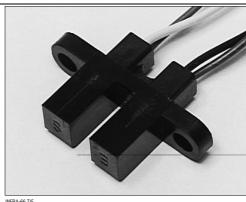
All devices employ a built-in strain relief for maximum wire attachment strength. The HOA088X series utilizes an IR transmissive polysulfone housing which features smooth optical faces without external aperture openings; this feature is desirable when aperture blockage from airborne contaminants is a possibility. The HOA089X series employs an opaque polysulfone housing with aperture openings for use in applications in which maximum rejection of ambient light is important and in situations where maximum position resolution is desired. The HOA088X/089X series employs plastic molded components. For additional component information see SEP8506 and SDP8406.

Housing material is polysulfone. Housings are soluble in chlorinated hydrocarbons and ketones. Recommended cleaning agents are methanol and isopropanol.

The detector to emitter lead spacing is 0.32 in.(8.13 mm) for all versions. Wire color code and functions are:

Red - IRED Anode White - Detector Collector Black - IRED Cathode Green - Detector Emitter

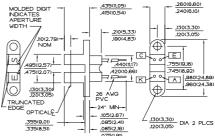
To specify the complete product characteristics, see PART NUMBER GUIDE.



#### **OUTLINE DIMENSIONS** in inches (mm)

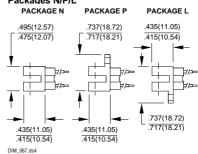
3 plc decimals ±0.010(0.25) Tolerance 2 plc decimals ±0.020(0.51)

# Package T



DIM 042 cdr

#### Packages N/P/L





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## ELECTRICAL CHARACTERISTICS (25°C unless otherwise noted)

ELECTRICAL CHARACTERISTICS (25 of united by the united by						
PARAMETER	SYMBOL	MIN	TYP	MAX	UNITS	TEST CONDITIONS
IR EMITTER						
Forward Voltage	VF			1.6	V	I <sub>F</sub> =20 mA
Reverse Leakage Current	IR			10	μΑ	V <sub>R</sub> =3 V
DETECTOR						
Collector-Emitter Breakdown Voltage	V <sub>(BR)</sub> ceo	30			V	Ic=100 μA
Emitter-Collector Breakdown Voltage	V <sub>(BR)ECO</sub>	5.0			V	I <sub>E</sub> =100 μA
Collector Dark Current	ICEO			100	nA	Vce=10 V, I <sub>F</sub> =0
COUPLED CHARACTERISTICS						
On-State Collector Current	Ic(on)				mA	
Parameter A		0.5				V <sub>CE</sub> =10, I <sub>F</sub> =20 mA
(HOA0880/0890)						
Parameter B		1.0				Vce=5 V, I <sub>F</sub> =10 mA
(HOA0881/0891)						
Parameter C		1.8				Vce=0.6, I <sub>F</sub> =20 mA
(HOA0882/0892)						
Collector-Emitter Saturation Voltage	VCE(SAT)				V	
Parameter A				0.4		I <sub>C</sub> =0.4 mA, I <sub>F</sub> =20 mA
(HOA0880/0890)						, ,
Parameter B				0.4		Ic=0.8 mA, I <sub>F</sub> =10 mA
(HOA0881/0891)						, , , , , , , , , , , , , , , , , , , ,
Parameter C				0.6		Ic=1.8 mA, I <sub>F</sub> =20 mA
(HOA0882/0892)						, ,, ==
Rise And Fall Time	t <sub>r</sub> , t <sub>f</sub>		15		μs	Vcc=5 V, lc=1 mA
	., .,		_		, -	R <sub>L</sub> =1000 Ω

#### **ABSOLUTE MAXIMUM RATINGS**

(25°C Free-Air Temperature unless otherwise noted)

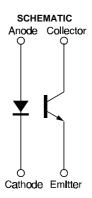
Operating Temperature Range -40°C to 85°C Storage Temperature Range -40°C to 85°C Soldering Temperature (5 sec) 240°C

IR EMITTER

Power Dissipation 100 mW (1)
Reverse Voltage 3 V
Continuous Forward Current 50 mA

DETECTOR
Collector-Emitter Voltage 30 V
Emitter-Collector Voltage 5 V

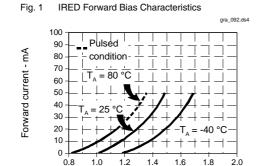
Emitter-Collector Voltage 5 V
Power Dissipation 100 mW <sup>(1)</sup>
Collector DC Current 30 mA



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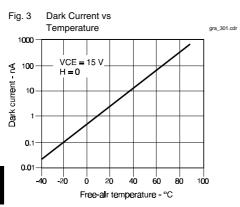
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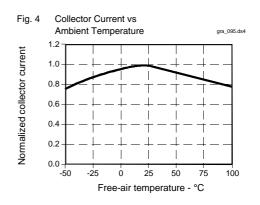
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Forward voltage - V

Fig. 2 Non-Saturated Switching Time vs Load Resistance gra\_093.ds4 Response time - us +1+1# 11111111 TI TIT  $\exists \mp \Box \Box$  $\Pi \Pi \Pi \Pi$ 100 10 Load resistance - Ohms





All Performance Curves Show Typical Values

\*0.010 in. (.25 mm) aperture available

with electrical Parameter A only

### PART NUMBER GUIDE

# HOA08XX-XXX

# Housing Material 8 = Polysulfone, IR transmissive 9 = Polysulfone, opaque Electrical Specifications 0 = Parameter A 1 = Parameter B 2 = Parameter C

Aperture length is 0.060 in. (1.52 mm)

Aperture Width In Front Of IRED

5 = 0.050 in. (1.27 mm)

Aperture length is 0.060 in. (1.52 mm)

Aperture Width In Front Of Detector

\*1 = 0.010 in. (0.25 mm)

5 = 0.050 in. (1.27 mm)

Aperture length is 0.060 in. (1.52 mm)

Mounting Configuration

L = Single mounting tab, emitter side

N = No mounting tabs
P = Single mounting tab, detector side
T = Two mounting tabs

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